

Technical Data Data Sheet N0393, Rev. - **Green Products**

SDURB1040CT ULTRAFAST PLASTIC RECTIFIER

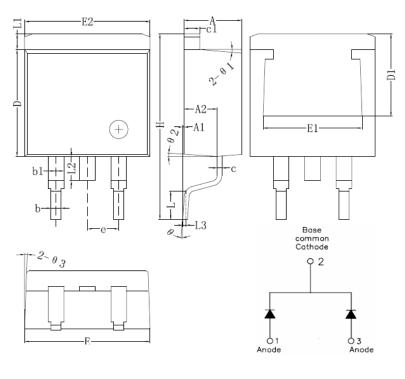
Applications:

- Antiparallel diode for high frequency switching devices
 - Anti saturation diode
 - Snubber diode
- Free wheeling diode in converters and motor control circuits
- Rectifiers in switch mode power supplies (SMPS)
- Inductive heating and melting
- Uninterruptible power supplies (UPS)
- Ultrasonic cleaners and welders

Features:

- Ultra-Fast Switching
- High Current Capability
- Low Reverse Leakage Current
- High Surge Current Capability
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Mechanical Dimensions: In mm



Symbol	Dimensions in			
	millimeters			
	Min.	Typical	Max.	
Α	4.55	4.70	4.85	
A1	0	0.10	0.25	
A2	2.59	2.69	2.89	
b	0.71	0.81	0.96	
b1		1.27		
С	0.36	0.38	0.61	
c1	1.17	1.27	1.37	
D	8.55	8.70	8.85	
D1	6.40			
E	10.01	10.16	10.31	
E1	7.6			
E2	9.98	10.08	10.18	
е		2.54		
Н	14.6	15.1	15.6	
L	2.00	2.30	2.70	
L1	1.17	1.27	1.40	
L2			2.20	
L3		0.25BSC		
е	0	-	8°	
e1		5°		
e2		4 °		
e3		4 °		

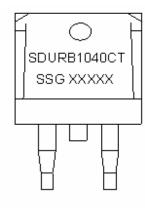
 $D^2 PAK$



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Marking Diagram:



Where XXXXX is YYWWL

SDUR	= Device Type
В	= Package type
10	= Forward Current (10A)
40	= Reverse Voltage (400V)
CT	= Configuration
SSG	= SSG
YY	= Year
WW	= Week
L	= Lot Number

Cautions: Molding resin Epoxy resin UL:94V-0

Ordering Information:

Device	Package	Shipping	
SDURB1040CT	D ² PAK	800maa/ raal	
	(Pb-Free)	800pcs/ reel	

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	V _{RWM}	-	400	V
Max. Average Forward	lo _(AV)	50Hz, Sine wave, T _C =112℃	10	А
Max. Peak One Cycle Non- Repetitive Surge Current (per leg)	I _{FSM}	50Hz, Half Sine wave	80	A



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Electrical Characteristics:

Characteristics	Symbol	Condition	Max.	Units
Max. Forward Voltage Drop (per leg)	V _F	@ I _F = 5A, Pulse, T _J = 25 $^{\circ}$ C	1.3	V
Max. Reverse Current	I _R	@V _R = rated V _R T _J = 25℃	30	μA
Max. Reverse Recovery Time	t _{rr}	I_F =500mA, I_R =1A,and I_{rm} =250mA	45	ns

 $^{*}\,$ Pulse width < 300 $\mu s,\,$ duty cycle < 2%

Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Max. Junction Temperature	TJ	-	-55 to +150	°C
Max. Storage Temperature	T _{stg}	-	-55 to +150	°C
Maximum Thermal Resistance Junction to Case	$R_{ ext{ heta}JC}$	DC operation	3.5	°C /W
Approximate Weight	wt	-	1.85	g
Case Style		D2PAK		

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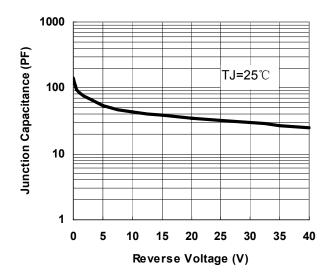


Fig.1-Typical Junction Capacitance

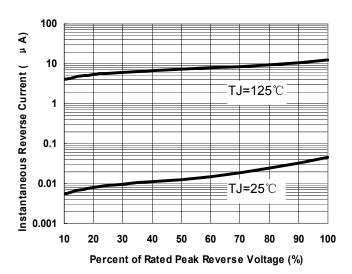


Fig.2-Typical Reverse Characteristics

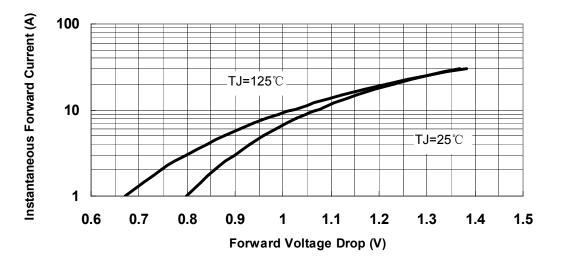


Fig.3-Typical Instantaneous Forward Voltage Characteristics



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